

Supplementary Information

Strain-engineered thermophysical properties ranging from band insulating to topological insulating phases in β -Antimonene

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1. Crystal Orbital Hamiltonian Population (COHP)

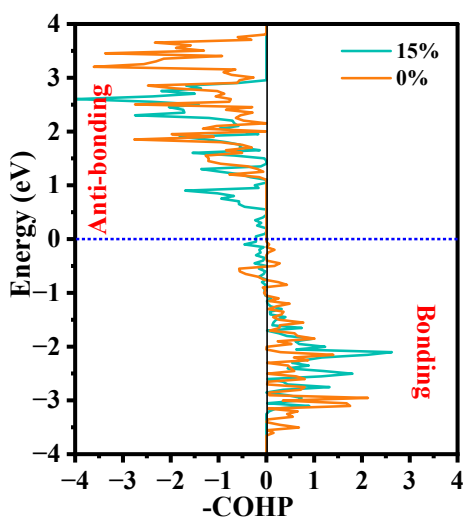


Fig. S1: The Crystal Orbital Hamiltonian Population comparing (-COHP) for 0% to 15 % strain. Near fermi level the relatively larger population of the antibonding states at 15% strain indicate the weakening in covalent bond leading a anharmonicity.

2. Mechanical & Structural Properties:

Table S1: Elastic stiffness Coefficients, bulk modulus (B), density (ρ), the sound velocity in transverse (v_t) and longitudinal direction (v_l) for the pristine and strained β -Sb system.

Strain	C_{11} (N m ⁻¹)	C_{12} (N m ⁻¹)	C_{66} (N m ⁻¹)	B (N m ⁻¹)	ρ (kg m ⁻²)	Poisson ratio	v_t (km s ⁻¹)	v_l (km s ⁻¹)
0%	32.746	6.395	13.176	19.571	2.75×10^{-6}	0.195	2.18	3.45
5%	23.761	5.619	9.071	14.690	2.54×10^{-6}	0.236	1.90	3.09
10%	17.018	4.234	6.392	10.626	2.27×10^{-6}	0.248	1.68	2.74
15%	6.259	1.099	2.580	3.679	2.08×10^{-6}	0.176	1.13	1.73

The average sound velocity in the crystal is given by;

$$v_s = \left[\frac{1}{3} \left(\frac{1}{v_l^3} + \frac{2}{v_t^3} \right) \right]^{-\frac{1}{3}} \#(1)$$

Where v_l and v_s are the longitudinal and transverse sound velocity and given as follows;

$$v_l = \left(\frac{B + G}{\rho_{2D}} \right)^{\frac{1}{2}} \#(2)$$

$$\text{② } v_t = \left(\frac{G}{\rho_{2D}} \right)^{\frac{1}{2}} \#(3)$$

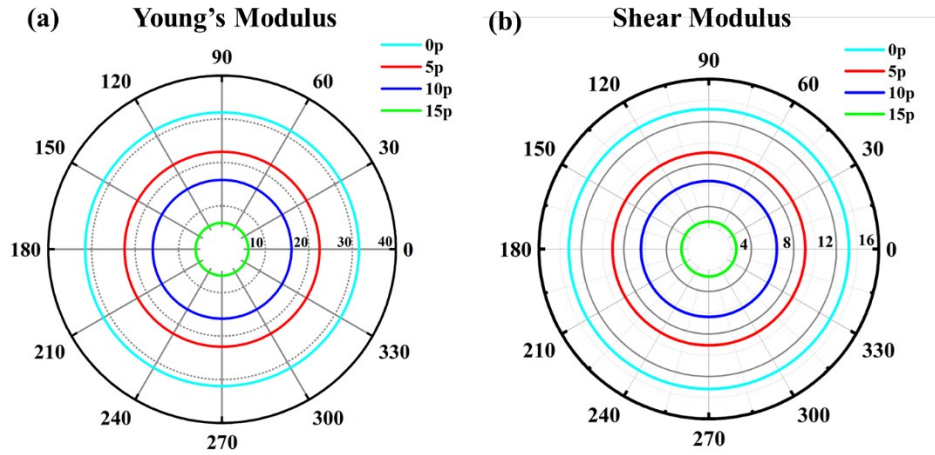


Fig. S2: The isotropic Young's Modulus (Y) and Shear Modulus (G) for the range of strain 0% to 15%. A reduction in its value indicates the reduction in bond strength with increasing biaxial strain.

3. Biaxial strain effect on Bandgap:

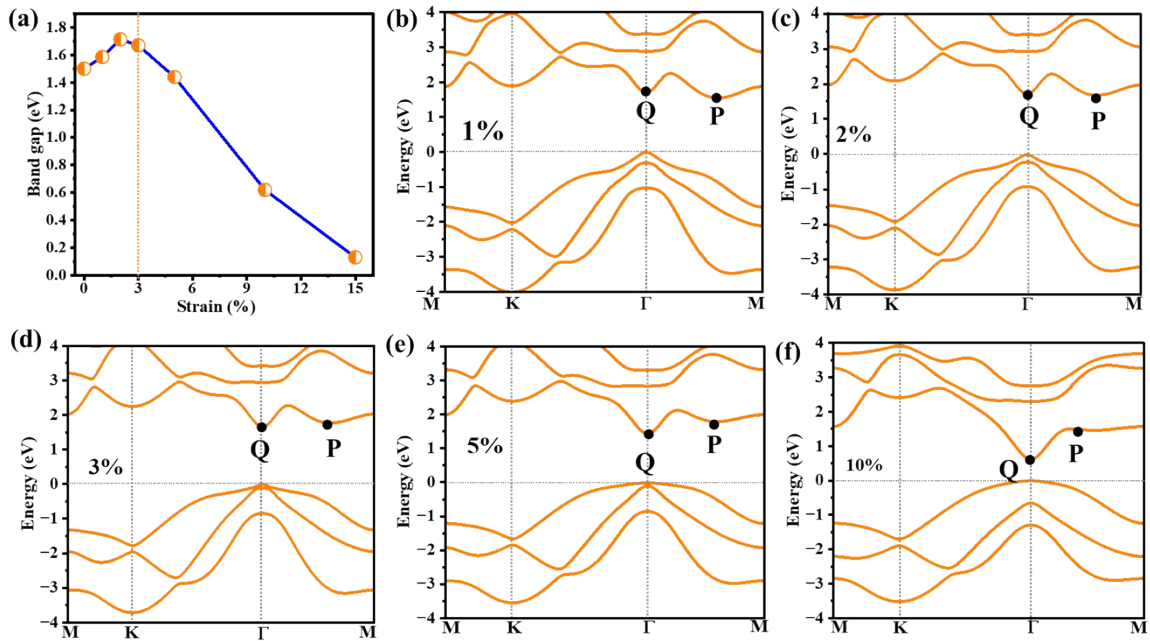


Fig. S3: Biaxial strain effect on the bandgap value (HSE06) for the range of strain 0% to 15% in β -Sb monolayer. The dotted vertical line shows indirect to direct bandgap transition at \sim 3% strain (b-f) Calculated HSE06, the electronic band structure of β -Sb including SOC for different strain (b) 1% strain (c) 2% strain (d) 3% strain (e) 5% strain (f) 10% strain.

4. Z2 Invariant in topological insulator:

In two-dimensions, to distinguish the quantum spin Hall phase from the band insulator, the Z_2 invariant is defined. Following Fu et al. approach, Z_2 invariant can also be determined in the presence of inversion symmetry, through parity of the occupied band eigenstates at the four time-reversal invariant momenta (TRIM) Γ_i points. This can be given by the quantities.

$$\delta_i = \prod_{m=1}^N \xi_{2m}(\Gamma_i) \#(4)$$

Where, $\xi_{2m}(\Gamma_i) = \pm 1$ is the parity eigenvalue of the $2m^{\text{th}}$ occupied energy band at Γ_i . The Z_2 invariant $\nu = 0, 1$ which determine the quantum spin-Hall phase, and is given as the product of δ_i 's.

$$(-1)^\nu = \prod_i \delta_i \#(5)$$

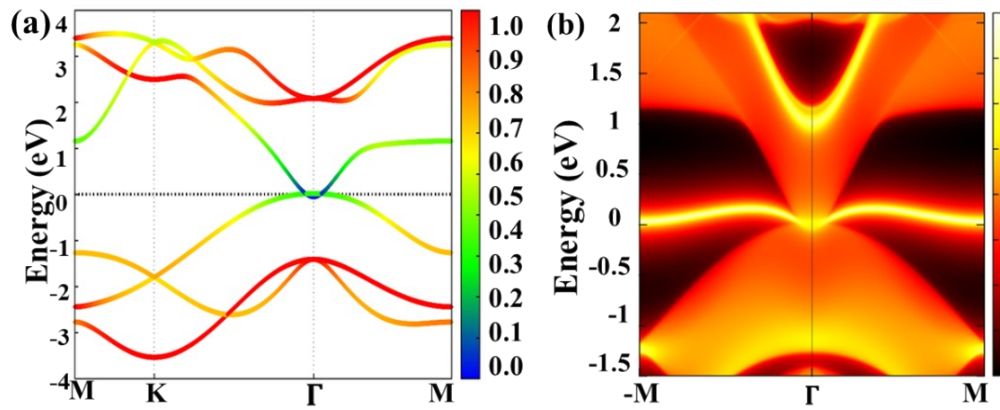


Fig. S4: (a) HSE06 based (without considering spin-orbit coupling) orbital projected band structure of β -Sb monolayer at 15% strain when no spin-orbit coupling is considered. The red colour denotes the complete p-orbital contribution. The dotted line indicates the fermi level. (b) Surface DOS for the 15% case within -1.5 eV to 2 eV energy range. The bright yellow region near fermi level signifies the two branches of overlapped edge states.

5. Weighted Phase space of phonon-phonon scattering:

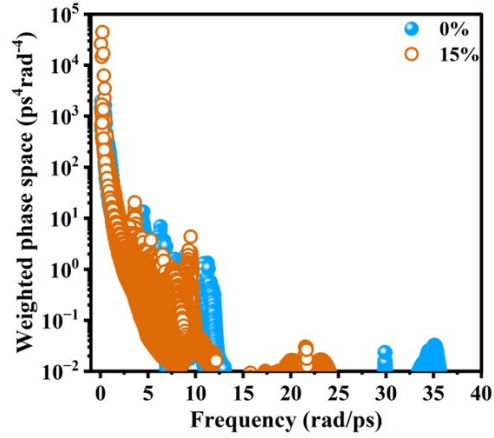


Fig. S5: Weighted phase space vs frequency (rad/ps) curve for 0% and 15% tensile strain.

6. Mild Strain Raman Spectra

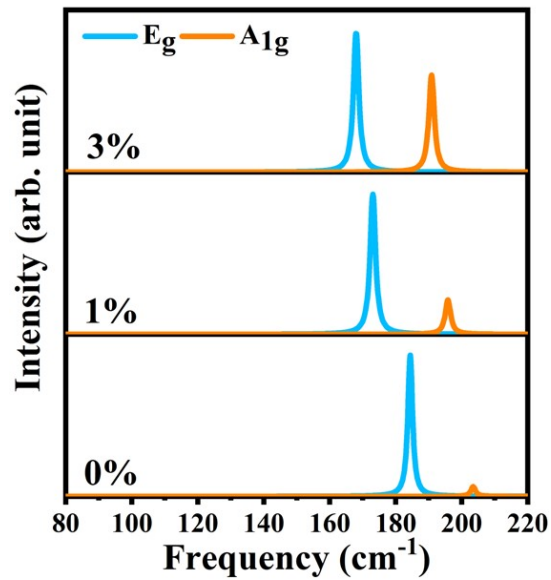


Fig. S6: Calculated Raman spectra as a function of frequency (cm⁻¹), under mild tensile strain ranging 0%, 1% and 3%. Orange and blue peaks represent the A_{1g} and E_g modes, respectively.

